

## **LEAD-FREE / RoHS-COMPLIANT**

### **HIGH POWER BIAS TEE**

**BTN2-0050** 

The BTN2-0050 is constructed using a custom-made, resonance-free conical inductor to achieve extremely broadband performance. By minimizing the overall inductor size and using proprietary packaging techniques, the BTN2-0050 is a superior option in terms of performance, reliability and ease-of-use when compared to cumbersome user-designed bias tees employing off-the-shelf conical inductors. The extremely low cutoff and resonance free operation makes the BTN2-0050 suitable for biasing amplifiers, lasers, and modulators driven with high frequency data patterns.



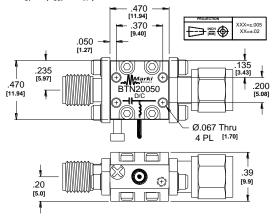
#### **Features**

- Broadband: 3 MHz to 50 GHz
- Low Insertion Loss
- High Power
- Non-Resonant
- Compact Size

**Electrical Specifications -** Specifications guaranteed from -55 to +100 $^{\circ}$ C, measured in a 50 $\Omega$  system.

Parameter	Frequency Range	Min	Тур	Max
Insertion Loss (dB)	10 MHz-50 GHz		1.5	2.5
	3-10 MHz		2	
DC Port Isolation (dB)	3 MHz -1 GHz		50	
	1-50 GHz		30	
Return Loss (dB)	0.141		13	
RF Power (W)	3 MHz-50 GHz			5
DC Current (A)				2
DC Voltage (V)				50
DC Resistance (Ω)			0.3	
Inductance (uH)			4.7	
Capacitance (nF)			100	
Weight (g)			10	
Risetime /Falltime (ps) <sup>1</sup>	2 2		10	

<sup>&</sup>lt;sup>1</sup>Specified as 90%/10%. Calculated from  $\tau_{bt}^2 = (\tau_{out}^2 - \tau_{in}^2)$ 



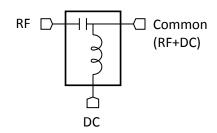


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### **Schematic**



### **Application Examples**

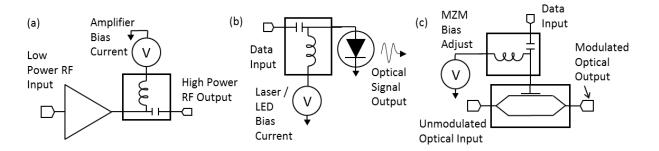


Fig. 1. Example Schematics of a) Broadband Microwave Amplifier Biasing, b) Laser/LED Biasing for Data Communication and c) Mach-Zender Modulator Biasing for Data Communication

### **Typical Performance**

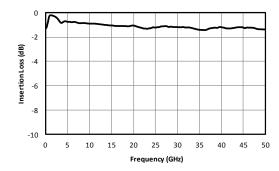


Fig. 2. RF insertion loss.

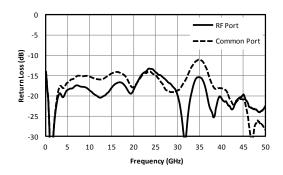


Fig. 3. Return loss.



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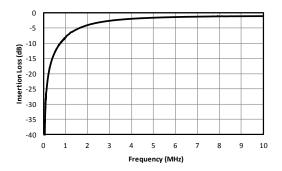


Fig. 4. Low frequency RF response.

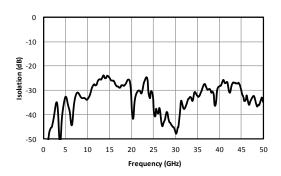


Fig. 6. DC-RF isolation.

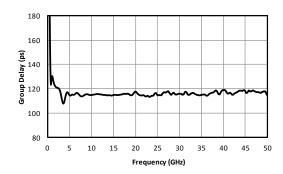


Fig. 8. Group delay.

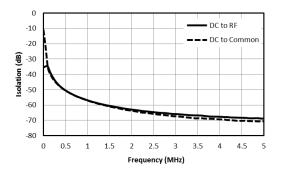


Fig. 5. Low frequency isolation.

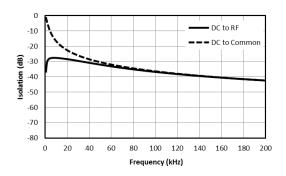


Fig. 7. Near DC isolation

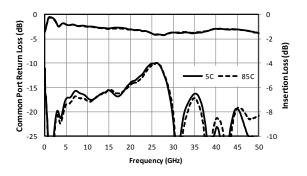


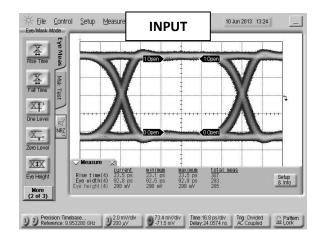
Fig. 9. Performance over temperature



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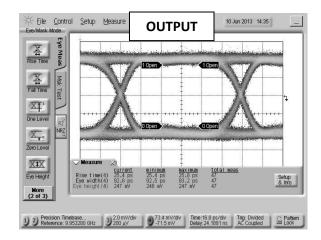


Fig. 7. Oscilloscope measurements of the BTN2-0050 with a 10Gb/s PRBS pattern. Eye diagrams are taken with a  $2^{31}$ -1 PRBS input demonstrating minimal eye distortion/closure afforded by the extremely low frequency operation of the bias tee.

Model Number	Description	
BTN2-0050	3 MHz to 50 GHz High Power Bias Tee	
	with 2.4 mm connectors <sup>1</sup> , LEAD-FREE/RoHS COMPLIANT	

<sup>&</sup>lt;sup>1</sup>Consult factory for other connector options.

### **Revision History**

Revision code	Revision Date	Comment
В	September 2019	RoHS Compliant Assembly

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